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FOREIGN PATENT DOCUMENTS

		Document	Date	Country	Class	Sub-class	Translation Yes/No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

AM		IEEE Journal of Selected Topics in Quantum Electronics; Hideyoshi Horie, et al.; "Reliability Improvement of 980-nm Laser Diodes with a New Facet Passivation Process"; vol. 5; p. 832 (1999)
		IEEE Journal of Quantum Electronics; Hiro O. Yonezu, et al.; "An AlGaAs Window Structure Laser"; vol. QE-15; p. 775 (1979)
		IEEE Journal of Selected Topics in Quantum Electronics; Kiyohisa Hiramoto, et al.; "High-Power and Highly Reliable Operation of A1-Free InGaAs-InGaAsP 0.98-μ Lasers with a Window Structure Fabricated by Si Ion Implantation"; vol. 5; p. 817 (1999)
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